"CMAD", a Full Custom ASIC for the Upgrade of COMPASS RICH-1

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Abstract

An 8 channel, full-custom ASIC prototype, named "CMAD", designed for the readout of the RICH-I detector system of the COMPASS experiment at CERN is presented.

The task of the chip is amplifying the signals coming from fast multi-anode photomultipliers and comparing them against a threshold adjustable on-chip on a channel by channel basis.

CMAD, developed using a 350nm commercial CMOS technology, occupies an area of $4.7x3.2mm^2$ and consumes 26mW/Ch power from a 3.3 V single source.

I. Introduction

COMPASS [1] is an experiment at the CERN SPS designed to study the structure and spectroscopy of hadrons with diverse types of high intensity beams. One of the key components of the experimental apparatus is a Ring Imaging CHerenkov (RICH) detector, used to perform particle identification.

In order to improve the reconstruction efficiency of the RICH, an upgrade is under development [2]. The experience gained with the first physics runs has, in fact, shown that a trigger rate of $100\ kHz$ and a single channel rate of $5\ MHz$ should be sustained in order to reach optimal performance. These tight requirements can be achieved by detecting the photons produced in the sensitive volume by photomultiplier tubes equipped with fast read-out electronics. The granularity of the system demands the use of compact multi-anode photomultipliers (MPT). The increased event rate that the system has to cope with has motivated the development of a new front end (FE) ASIC. This chip will replace the MAD-4 [3] presently used in the read-out of the RICH-I.

This chip named CMAD is presented in this paper. Produced in AMS 0.35 μm CMOS technology, the chip performs binary read-out of the MPT signals.

Section II gives an architectural overview. Section III deals with circuit design. Section IV summarizes preliminary test results.

II. ARCHITECTURE

Fig. 1 shows the architecture of a single channel. Each processing channel features a low-noise transimpedance amplifier followed by a shaper with $10\ ns$ peaking time, a baseline restorer, a comparator, a programmable oneshot and an LVDS driver.

The gain of the preamplifier can be adjusted from 0.4 mV/fC to 1.2 mV/fC in steps of 0.08 mV/fC. This allows

to compensate at least partially for the channel-to-channel gain variation of the MPTs. Additionally, the threshold of each comparator can be adjusted on a channel by channel basis via a local 8-bit digital to analog converter (D/A). The gain of the front-end and the D/A codes are programmed using a digital control unit and the I2C standard.

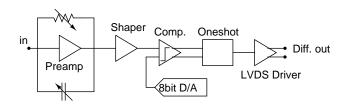


Figure 1: Binary read-out architecture of a single channel.

The fast shaper shown in Fig. 2 is based on a class AB operational amplifier [4] around which two feedback networks are implemented. A fast path performs high frequency filtering while a slow feedback provides the AC coupling with the previous stage and guarantees baseline stabilization [5].

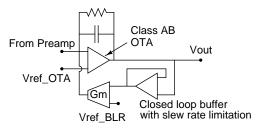


Figure 2: Architecture of the shaper in the channel.

A fast unity gain buffer with limited slew rate is used in the baseline control loop. Fast output signals at the output of the shaper are clipped before arriving at the transconductor stage. The baseline stabilization circuit is designed to reduce the baseline shift to less than 3 mV for output pulses with a 3 V amplitude and $10\ MHz$ rate.

The peaking time at the output of the shaper is $10 \ ns$. The system has been designed to cope with a rate in excess of $5 \ MHz/Ch$. The output pulses are stretched by a programmable one-shot and sent to an output stage able to drive long twisted pair cables with LVDS compatible levels (Fig. 1).

III. CIRCUIT DESIGN

Fig. 3 shows the implementation of OTA used within the shaper. The class AB CMOS OTA circuit dissipates 3 mW of

static power from a 3.3 Volts power supply and drives a 10 pF load with a slew rate of more than 500 $V/\mu s$.

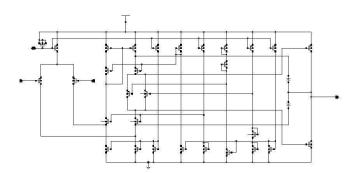


Figure 3: CMOS AB class OTA.

In the binary architecture given in Fig. 1, a global D/A can not be used since each of the read-out channels needs its own comparator that operates independently from the rest. This brings the necessity of a low power and small area D/A architecture, since it would be used for each read-out channel and thus more than once per chip.

Conceptually, the simplest D/As use a binary-weighted architecture, where n-binary weighted elements (current sources, resistors or capacitors) are combined to provide an analog output (n = D/A resolution). Digital encoding circuits are minimized, but the difference between the MSB and the LSB weights increase with increasing resolution, making accurate element matching difficult.

Among others like Kelvin divider or segmented architectures, the R-2R, or ladder, architecture relaxes component-matching requirements since only two component values are required in a 2:1 ratio. The R-2R architecture can be configured as a voltage- or current-mode D/A, together with different advantages and disadvantages.

A drawback of a current-mode R-2R architecture is the inversion introduced by the opamp which usually exists as an output current-to-voltage converter. Another disadvantage is the complicated stabilization of the opamp due to the fact that the D/A output impedance varies with digital input code. Current mode operation also results in higher glitch, since the switches connect directly to the output.

Advantage of voltage-mode R-2R configuration is that the output voltage has constant impedance, thus simplifying amplifier stabilization. Glitch generated by switch capacitance is also minimized. The drawback of voltage-mode R-2R configuration is that the reference input impedance varies widely, so a low-impedance reference must be used. Also, the switches operate from ground to Vref, restricting the allowed range of the reference.

CMAD implementation employs Low Drop-Out regulators (LDOs) for setting the reference voltage and bias current of the D/A together with other blocks. The technology used (0.35 μm) has relatively a high analog performance compared to recent low feature size technologies, so the amplifier compensation is easily achievable for the whole operation range. Relatively a high

accuracy of matching is also feasible with proper layout.

Concerning the above discussion, CMOST-only current-mode R-2R architecture is a suitable solution as it is composed of only transistors that are compact and that consume very low power. An important concern is also the output impedances driving the comparator, namely the outputs of the shaper and the D/A. For proper functioning of the comparator input stage which is basically a differential pair, it is desired to equalize these impedances. The shaper has a low output impedance, thus requiring the same for the D/A.

Fig. 4 shows conceptually the architecture of the small arealow power 10-bit D/A used for setting the threshold of the comparator [6]. In such an architecture, transistors in the ladder do not necessarily emulate identical resistor values but instead, successful operation is based on linear current division principle [7]. The accuracy of the division technique used is based on the characteristic I-V curve matching of the two transistors but not on their linearity [8].

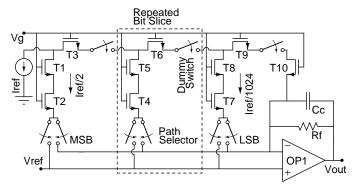


Figure 4: 10b CMOS-Only R-2R architecture.

In operation, first two MSBs are set globally together with the base line and the effective resolution required by the channel is 8 bits. Additional pads are also provided for the flexibility of disabling the on-chip LDO reference to be able to apply external sources. The LSB, thus the resolution, of the D/A can be adjusted for different conditions, in this way.

Power consumption of the D/A in Fig. 4 is approximately 1.1 mW including the opamp. A current mirror implementation with the same functionality and power consumption would exhibit a much larger output impedance. CMOST-only R-2R core operates with 50 μA of current which is negligible compared to the one consumed by the opamp.

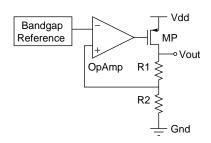


Figure 5: LDO voltage reference.

On-chip biasing is implemented via reference sources based on LDOs driven by band-gap voltage sources, as seen in Fig. 5. Linear voltage regulators use an active pass element (MP) to reduce the input voltage (Vdd) to the regulated output voltage (V_{OUT}). Linear voltage regulators force a fixed voltage level to appear at the output terminal.

The LDOs implemented for CMAD are optimized for subcircuit requirements and consume $0.9\ mW$ from $3.3\ V$ single source.

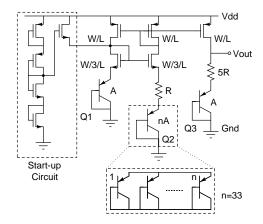


Figure 6: Implemented opamp-less band-gap reference.

Fig. 6 shows the implementation of the opamp-less bandgap reference driving the LDOs. The reference voltage output is given as $V_{REF} = V_{BE3} + 5V_T ln(n)$ where V_{BE3} is the B-E potential difference of Q3, V_T is the thermal voltage and n (=33) is the area ratio between Q2 and Q1. Band-gap in Fig. 6 consumes 93 μW from 3.3 V single source.

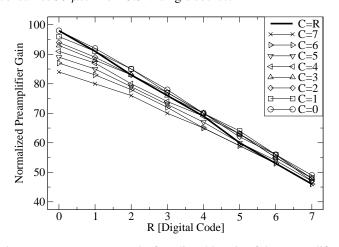


Figure 7: Measurement results for adjustable gain of the preamplifier as a function of R and C binary D/A converter inputs.

IV. TEST RESULTS

Measurements showed good agreement with simulation results. Gain and the output pulse shape of the preamplifier is adjustable by controlling the values of capacitive and resistive components in the feedback path. These component values can be set either independently or in a correlated manner in order to preserve the shape of the output signal.

The gain of the preamplifier is a strong function of the resistor as seen in Fig. 7. Gray curves show the gain variation due to change in resistor while the capacitor value is preserved. In order to keep the signal with the optimum shape, the capacitor should be adjusted in such a way that the time constant remains the same. The black curve (R=C) shows the gain for which the digital inputs are equal, thus the output signal shape is maintained. As seen in Fig. 8, capacitor value has only a slight effect on the preamplifier gain. It is utilized to adjust the time constant but not the gain itself. An increase in the binary code for resistor must be accompanied by an increased capacitor code. Reverse logic is used internally in the chip to preserve the direction of the digital code change maintaining optimum signal shape.

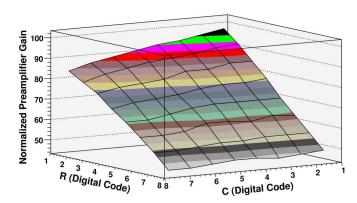


Figure 8: Measurement results for adjustable gain of the preamplifier as a function of R and C binary D/A converter inputs.

Linearity of the preamplifier output is important for proper operation. Fig. 9 shows the measurement results. In the upper plot, circles represent the normalized preamplifier output values and the solid line is the linear fit. The nonlinearity is less than 2%, as seen in residual between data and linear fit given at the bottom.

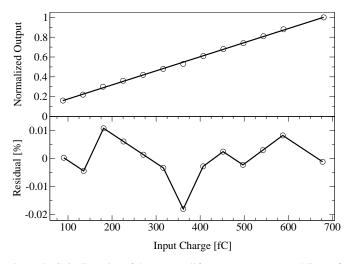


Figure 9: Gain linearity of the preamplifier; measurement and linear fit (upper plot) and the difference between fit and measurement.

V. CONCLUSION

An 8 channel, full-custom ASIC prototype, named CMAD, designed for the readout of the RICH-I detector system of the COMPASS experiment at CERN is presented.

In CMAD, threshold of each channel can be adjusted independent from the other channels. Thanks to low noise preamplifier, lower thresholds can be set individually to improve frontend performance. Table 1 summarizes the specification details. The ASIC, shown in Fig. 10, implemented in AMS 0.35 μm commercial technology, occupies $4.7x3.2mm^2$ of area and consumes 26mW/Ch power from a 3.3 V single source.

Table 1:	CMAD	Specifications
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Technology	$0.35~\mu m$
Number of Channels	8/Chip
Preamplifier Gain Range	0.4- $1.2~mV/fC$
Preamplifier Gain Resolution	0.08~mV/fC
Peaking Time	$10 \ ns$
Speed	>5 MHz/Ch
Chip Size	$4.7x3.2 \ mm^2$
Power (w/o LVDS Drivers)	26~mW

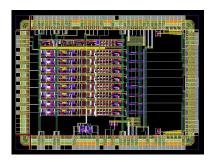


Figure 10: CMAD chip layout.

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